DS04-28209-2E

ASSP for Image Processing

CMOS

A/D Converter (1-channel, 8-bit, 30MHz)

MB40C568H

■ DESCRIPTION

The MB40C568H is a high-speed A/D converter using high-speed CMOS process technology.

■ FEATURES

- · Resolution: 8 bits
- Linearity error: ±0.20% (Typ.)
- Maximum conversion rate: 30 MSPS (Min.)
- Power supply voltage: Analog section +5.0 V
 - Digital section +3.0 V or +5.0 V
- Digital input voltage range: TTL level
- Digital output voltage range: CMOS level compatible
- Analog input voltage range: 0.5 to 4 V (with 2 Vp-p)
- Analog input capacity: 15 pF (Typ.)
- Power consumption: 90 mW (Typical: @fclk = 30 MHz, AVDD = 5 V, DVDD = 3 V)
 110 mW (Typical: @fclk = 30 MHz, AVDD = DVDD = 5 V)
- Additional function: Reference voltage generator circuit: VREFT = 3 V, VREFB = 1 V
- Package options: SOP24, SSOP24

■ PACKAGES

24-pin, Plastic SSOP

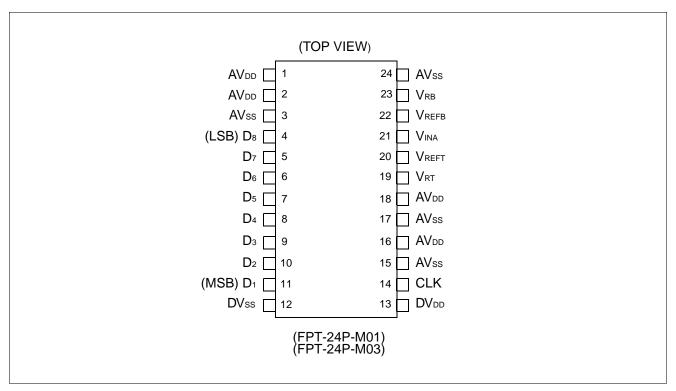
24-pin, Plastic SSOP

(FPT-24P-M01)

(FPT-24P-M03)

This device contains circuitry to protect the inputs against damage due to high static voltages or electric fields. However, it is advised that normal precautions be taken to avoid application of any voltage higher than maximum rated voltages to this high impedance circuit.

■ PIN ASSIGNMENT



■ PIN DESCRIPTION

Pin No.	Pin name	Functions
1, 2, 16, 18	AV _{DD}	Analog power supply pins (+5 V)
13	DV _{DD}	Digital power supply pin (+3 or +5 V)
3, 15, 17, 24	AVss	Analog power ground pins (0 V)
12	DVss	Digital power ground pin (0 V)
4 to 11	D ₁ to D ₈	Digital output pins. D ₁ : MSB, D ₈ : LSB
14	CLK	Clock input pin
21	VINA	Analog input pin. Input range: VRB to VRT (2 Vp-p between 0.5 to 4 V)
19	V _{RT}	Reference voltage input pin (3 V)
20	Vreft	Reference voltage output pin. When connected to VRT, the pin generates $0.6 \times \text{AV}_{\text{DD}}$ (3 V).
23	V _{RB}	Reference voltage input pin (1 V)
22	VREFB	Reference voltage output pin. When connected to VRB, the pin generates $0.2 \times \text{AV}_{\text{DD}}$ (1 V).

Values within () are typical values.

■ NOTES ON USE

- Be sure to bypass the AV_{DD}, DV_{DD}, V_{RT} and V_{RB} pins to the ground using a high-frequency capacitor. The high-frequency capacitor should be connected as near the pin as possible.
- Provide four clocks or more immediately after the power up to prevent current dissipation due to the indeterminate internal logic.

■ ABSOLUTE MAXIMUM RATINGS (See WARNING)

Parameter	Cymbol	Rat	ting	Unit
Parameter	Symbol	Min.	Max.	Ullit
Power supply voltage	AV _{DD} , DV _{DD}	-0.3	0.7	V
Input voltage	CLK, VINA Vrt, Vrb	-0.3	AVpp+0.3	V
Output voltage	D ₁ to D ₈	-0.3	DV _{DD} +0.3	V
Storage temperature	Tstg	- 55	+125	°C

WARNING: Semiconductor devices can be permanently damaged by application of stress (voltage, current, temperature, etc.) in excess of absolute maximum ratings. Do not exceed these ratings.

■ RECOMMENDED OPERATING CONDITIONS

Parameter	Symbol			Unit	
Farameter	Syllibol	Min.	Тур.	Max.	Offic
Analog input voltage	VINA	V_{RB}	_	V _{RT}	V
Analog reference voltage: T	V _{RT}	-	-	4.00	V
Analog reference voltage: B	V _{RB}	0.50	_	_	V
Analog reference voltage range	V _{RT} -V _{RB}	1.90	2.00	2.10	V
Digital "H" level input voltage	VIHD	2.4	-	-	V
Digital "L" level input voltage	VILD	_	_	0.8	V
Digital input current	lıd	_	_	5	μΑ
Clock frequency	fclk	0.1	-	30	MHz
Minimum "H" level clock pulse width	tw+	14.0	_	_	ns
Minimum "L" level clock pulse width	tw-	14.0	-	-	ns
Operating temperature range	Та	-20	_	70	°C

WARNING: Recommended operating conditions are normal operating ranges for the semiconductor device. All the device's electrical characteristics are warranted when operated within these ranges.

Always use semiconductor devices within the recommended operating conditions. Operation outside these ranges may adversely affect reliability and could result in device failure.

No warranty is made with respect to uses, operating conditions, or combinations not represented on the data sheet. Users considering application outside the listed conditions are advised to contact their FUJITSU representative beforehand.

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When using a single power supply

Parameter	Symbol		Value		Unit
r ai ainetei	Min.		Тур.	Max.	Olik
Power supply voltage	AV_{DD}, DV_{DD}	4.75	5.00	5.25	V

When using dual power supplies

Parameter	Symbol		Unit		
Farameter	Syllibol	Min.	Тур.	Max.	Oilit
Dower aupply voltage	AVDD	4.75	5.00	5.25	V
Power supply voltage	DV _{DD}	2.70	3.00	3.30	V

WARNING: Recommended operating conditions are normal operating ranges for the semiconductor device. All the device's electrical characteristics are warranted when operated within these ranges.

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No warranty is made with respect to uses, operating conditions, or combinations not represented on the data sheet. Users considering application outside the listed conditions are advised to contact their FUJITSU representative beforehand.

■ ELECTRICAL CHARACTERISTICS (Using a Single Power Supply)

DC Characteristics

(1) Analog section

 $(AV_{DD} = DV_{DD} = 4.75 \text{ V to } +5.25 \text{ V}, \text{ Ta} = -20^{\circ}\text{C to } +70^{\circ}\text{C})$

Parameter		Symbol			Unit	
Parameter	Parameter		Min.	Тур.	Max.	Offic
Resolution		_	-	8	_	bit
Linearity error	DC precision	LE	_	±0.20	±0.30	%
Differential linearity error	DC precision	DLE	_	±0.12	±0.20	%
Analog input capacity	Analog input capacity		_	15	_	pF
Reference voltage: T		VREFT	_	$0.6 \times AV_{DD}$	_	V
Reference voltage: B		VREFB	_	$0.2 \times AV_{DD}$	_	V
Reference current		lпв	-16.0	-8.0	-2.0	mA
Analog power supply current		Aldd	_	16.0	28.0	mA
Digital power supply current		DIDD	-	6.0	10.0	mA

(2) Digital section

 $(AV_{DD} = DV_{DD} = 4.75 \text{ V to } +5.25 \text{ V}, \text{ Ta} = -20^{\circ}\text{C to } +70^{\circ}\text{C})$

Parameter	Symbol	Value			Unit
Farameter	Syllibol	Min.	Тур.	Max.	Ollit
Digital "H" level output voltage	Vohd	4.2	_	DV _{DD}	V
Digital "L" level output voltage	Vold	-	_	0.4	V
Digital "H" level output current	Іон	-400	_	_	μΑ
Digital "L" level output current	lol	_	_	1.6	mA

(3) Switching section

 $(AV_{DD} = DV_{DD} = 4.75 \text{ V to } +5.25 \text{ V}, \text{ Ta} = -20^{\circ}\text{C to } +70^{\circ}\text{C})$

Parameter	Symbol		Unit		
Farameter	Symbol	Min.	Тур.	Max.	Ollit
Maximum conversion rate	fs	30	_	_	MSPS
Digital output delay time	tpd	0	5	15	ns

■ ELECTRICAL CHARACTERISTICS (Using Dual Power Supplies)

DC Characteristics

(1) Analog section

 $(AV_{DD} = 4.75 \text{ V to } +5.25 \text{ V}, DV_{DD} = 2.70 \text{ V to } +3.30 \text{ V Ta} = -20^{\circ}\text{C to } +70^{\circ}\text{C})$

Parameter		Symbol		Unit		
Parameter	rarameter		Min.	Тур.	Max.	Offic
Resolution		_	-	8	_	bit
Linearity error	DC precision	LE	-	±0.20	±0.30	%
Differential linearity error	DC precision	DLE	_	±0.12	±0.20	%
Analog input capacity		CINA	-	15	_	pF
Reference voltage: T		V _{REFT}	-	$0.6 \times AV_{DD}$	-	V
Reference voltage: B		V _{REFB}	_	$0.2 \times AV_{DD}$	_	V
Reference current		lпв	-16.0	-8.0	-2.0	mA
Analog power supply current		Aldd	-	16.0	28.0	mA
Digital power supply current		DI _{DD}	1	4.0	7.0	mA

(2) Digital section

 $(AV_{DD} = 4.75 \text{ V to } +5.25 \text{ V}, DV_{DD} = 2.70 \text{ V to } +3.30 \text{ V Ta} = -20^{\circ}\text{C to } +70^{\circ}\text{C})$

Parameter	Symbol		Unit		
Farameter	Symbol	Min.	Тур.	Max.	Offic
Digital "H" level output voltage	Vohd	2.4	_	DV _{DD}	V
Digital "L" level output voltage	Vold	_	_	0.4	V
Digital "H" level output current	Іон	-400	_	_	μΑ
Digital "L" level output current	loL	_	_	1.6	mA

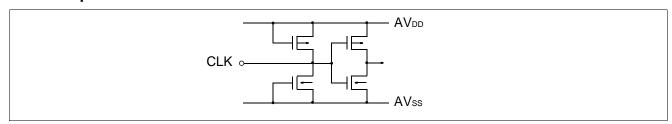
(3) Switching section

 $(AV_{DD} = 4.75 \text{ V to } +5.25 \text{ V}, DV_{DD} = 2.70 \text{ V to } +3.30 \text{ V Ta} = -20^{\circ}\text{C to } +70^{\circ}\text{C})$

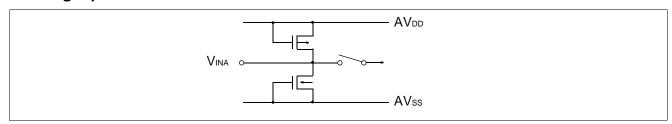
Parameter	Symbol		Unit			
raianietei	Symbol	Min.	Тур.	Max.	Oilit	
Maximum conversion rate	fs	30	_	_	MSPS	
Digital output delay time	tpd	0	6	18	ns	

■ EQUIVALENT CIRCUIT

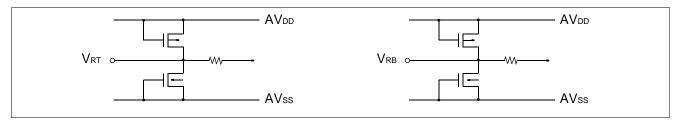
• Clock input



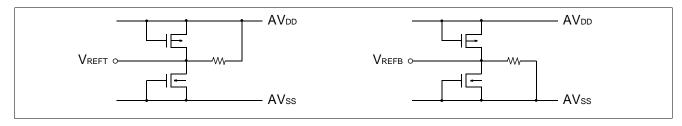
• Analog input



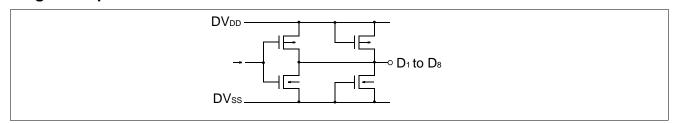
• Reference voltage input



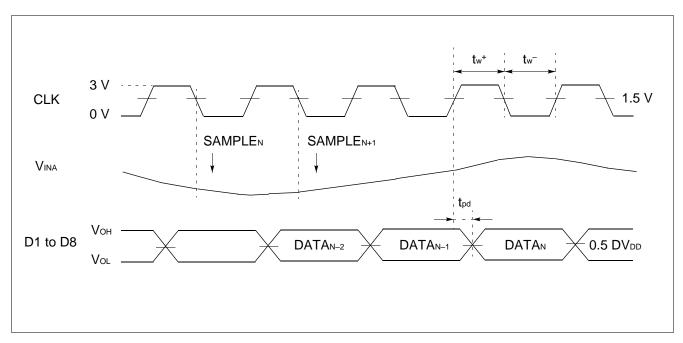
• Reference voltage output



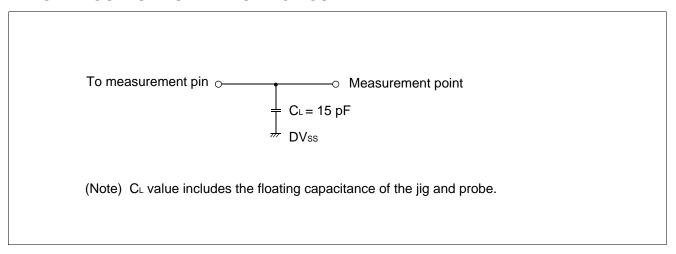
• Digital output



■ TIMING CHART



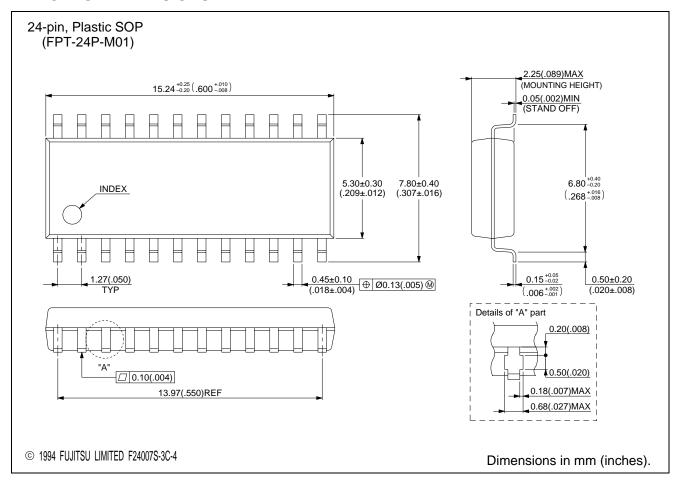
■ DIGITAL OUTPUT BUFFER LOAD CIRCUIT



■ ORDERING INFORMATION

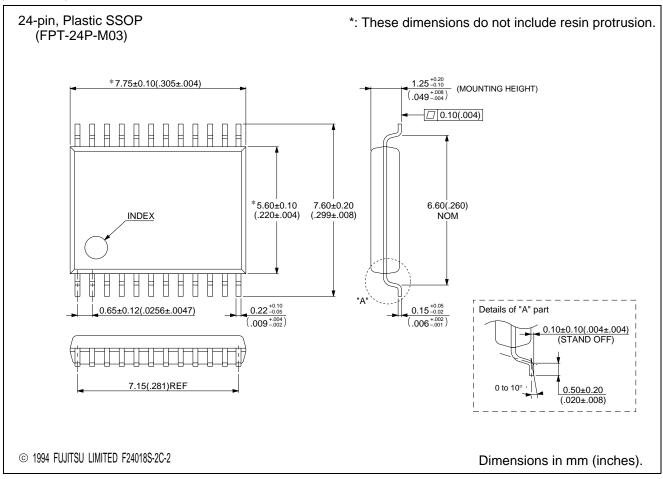
Part number	Package	Remarks
MB40C568HPF	24-pin, Plastic SOP (FPT-24P-M01)	
MB40C568HPFV	24-pin, Plastic SSOP (FPT-24P-M03)	

■ PACKAGE DIMENSIONS



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